MOTOROLA

HIGH-FREQUENCY CIRCUITS

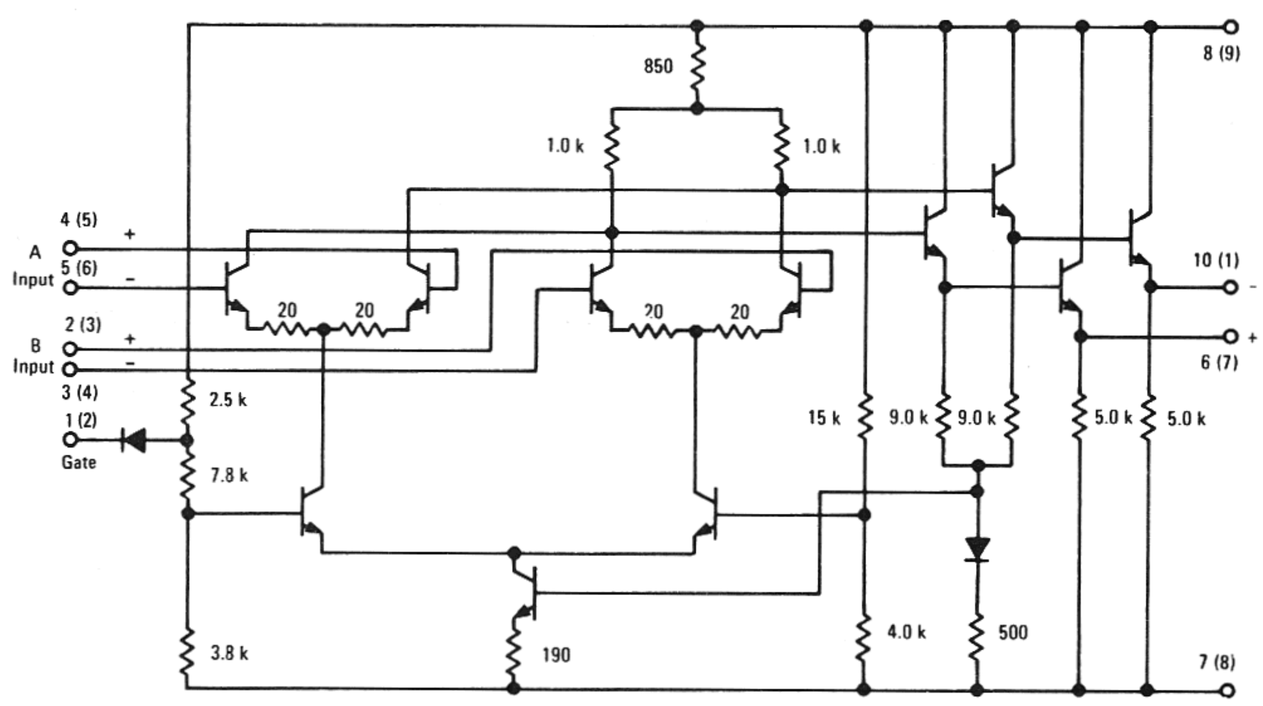
GATE CONTROLLED TWO-CHANNEL-INPUT WIDEBAND AMPLIFIER

MC1545
MC1445

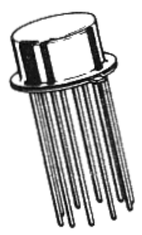
. . . designed for use as a general-purpose gated wideband-amplifier, video switch, sense amplifier, multiplexer, modulator, FSK circuit, limiter, AGC circuit, or pulse amplifier.

- Large Bandwidth; 75 MHz typical
- Channel-Select Time of 20 ns typical
- Differential Inputs and Differential Output

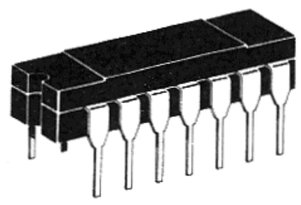
CIRCUIT SCHEMATIC



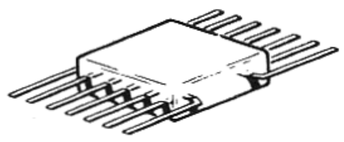
Number in parenthesis denotes pin for F and L packages, number at left in each case denotes corresponding pin for G package.



G SUFFIX
METAL PACKAGE
CASE 602A



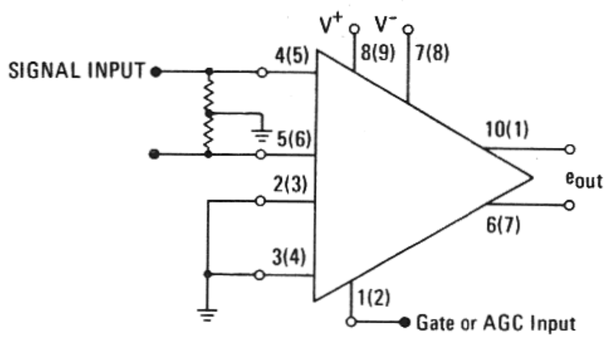
L SUFFIX
CERAMIC PACKAGE
CASE 632
TO-116



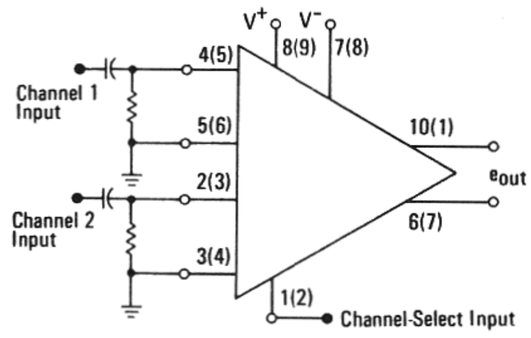
F SUFFIX
CERAMIC PACKAGE
CASE 607
TO-86

TYPICAL APPLICATIONS

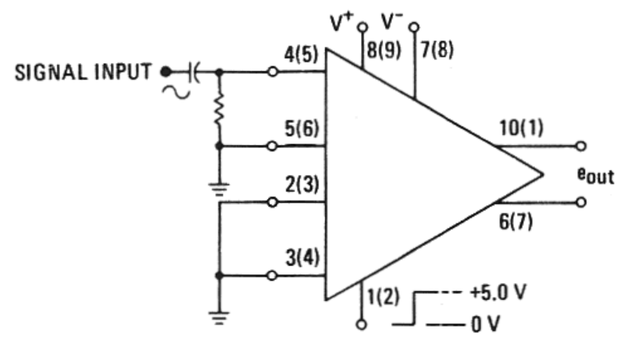
VIDEO SWITCH OR DIFFERENTIAL AMPLIFIER WITH AGC



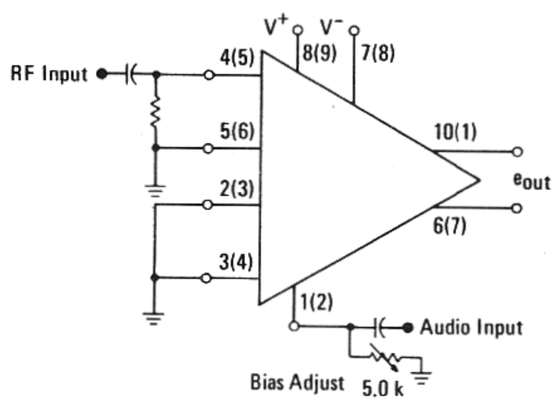
MULTIPLEX OR FSK



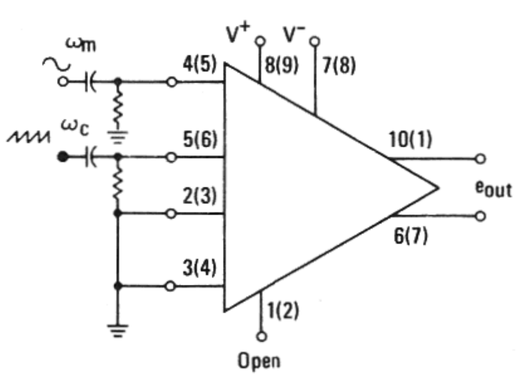
ANALOG SWITCH



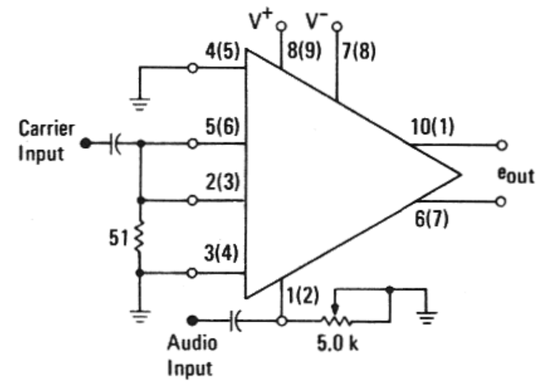
AMPLITUDE MODULATOR



PULSE-WIDTH MODULATOR



BALANCED MODULATOR



MC1545, MC1445 (continued)

MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Power Supply Voltage	V^+ V^-	+12 -12	Vdc Vdc
Differential Input Signal	V_{in}	±5.0	Volts
Load Current	I_L	25	mA
Power Dissipation (Package Limitation) Flat Package Derate above T_A = 25°C Ceramic Dual In-Line Package Derate above T_A = 25°C Metal Can Derate above T_A = 25°C	P_D	 500 3.3 625 5.0 680 4.6	 mW mW/°C mW mW/°C mW mW/°C
Operating Temperature Range MC1445 MC1545	T_A	0 to +75 -55 to +125	°C
Storage Temperature Range	T_{stg}	-65 to +150	°C

ELECTRICAL CHARACTERISTICS (V^+ = +5.0 Vdc, V^- = -5.0 Vdc, at T_A = 25°C, specifications apply to both input channels unless otherwise noted)

Characteristic		Fig. No.	Symbol	Min	Typ	Max	Unit
Single-Ended Voltage Gain	MC1445 MC1545	1, 12	A_V	16 16	19 18	22 20	dB
Bandwidth	MC1445 MC1545	1, 12	BW	– 50	75 75	– –	MHz
Input Impedance (f = 50 kHz)	MC1445 MC1545	5, 14	Z_{in}	3.0 4.0	10 10	– –	k ohms
Output Impedance (f = 50 kHz)		6, 15	Z_{out}	–	25	–	Ohms
Output Voltage Swing (R_L = 1.0 k ohm, f = 50 kHz)		4, 13	V_{out}	1.5	2.5	–	V_{p-p}
Input Bias Current ($I_b = (I_1 + I_2)/2$)	MC1445 MC1545	16	I_b	– –	15 15	30 25	μAdc
Input Offset Current		16	$\|I_{io}\|$	–	2.0	–	μAdc
Input Offset Voltage	MC1445 MC1545	17	$\|V_{io}\|$	– –	– 1.0	7.5 5.0	mVdc
Quiescent Output dc Level		17	V_{out}(dc)	–	0.2	–	Vdc
Output dc Level Change (Gate Voltage Change: +5.0 V to 0 V)		17	$\|\Delta V_{out}(dc)\|$	–	15	–	mV
Common Mode Rejection Ratio (f = 50 kHz)		9, 18	CM_{rej}	–	85	–	dB
Input Common Mode Voltage Swing		18	CMV_{in}	–	±2.5	–	V_p
Gate Characteristics Gate Voltage Low (See Note 1) Gate Voltage High (See Note 2)	 MC1445 MC1545 MC1445 MC1545	8	 V_{gOL} V_{gOH}	 0.20 0.45 – –	 0.40 0.70 1.3 1.5	 – – 3.0 2.2	Vdc
Gate Current Low (Gate Voltage = 0 V)	MC1445 MC1545	18	I_{GOL}	– –	– –	4.0 2.5	mA
Gate Current High (Gate Voltage = +5.0 V)	MC1445 MC1545	18	I_{GOH}	– –	– –	4.0 2.0	μA
Step Response (e_{in} = 20 mV) www.datasheetcatalog.com	MC1445 MC1545 MC1445 MC1545 MC1445 MC1545 MC1445 MC1545	19	t_{pd+} t_{pd-} t_r t_f 	– – – – – – – –	6.5 6.5 6.3 6.3 6.5 6.5 7.0 7.0	– 10 – 10 – 10 – 10	ns
Wideband Input Noise (5.0 Hz - 10 MHz, R_S = 50 ohms)		10, 20	$V_{n(in)}$	–	25	–	μVrms
DC Power Dissipation	MC1445 MC1545	11, 20	P_D	– –	70 70	150 110	mW

Note 1 V_{gOL} is the gate voltage which results in channel A gain of unity or less and channel B gain of 16 dB or greater.
Note 2 V_{gOH} is the gate voltage which results in channel B gain of unity or less and channel A gain of 16 dB or greater.

MC1545, MC1445 (continued)

FIGURE 1 – SINGLE-ENDED VOLTAGE GAIN versus FREQUENCY

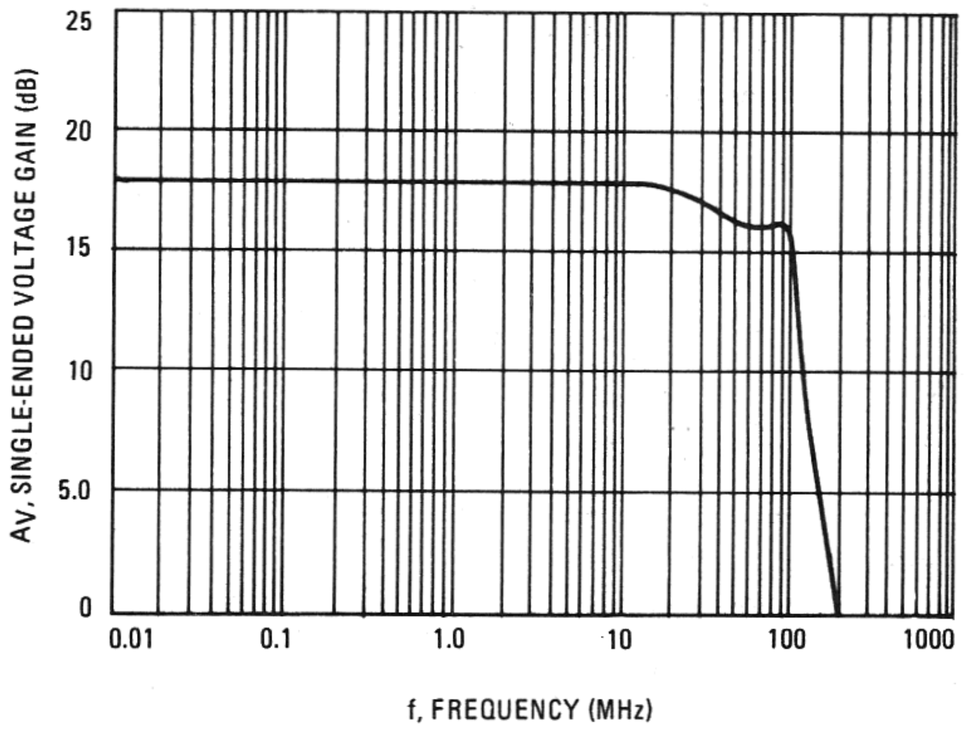


FIGURE 2 – SINGLE-ENDED VOLTAGE GAIN versus TEMPERATURE

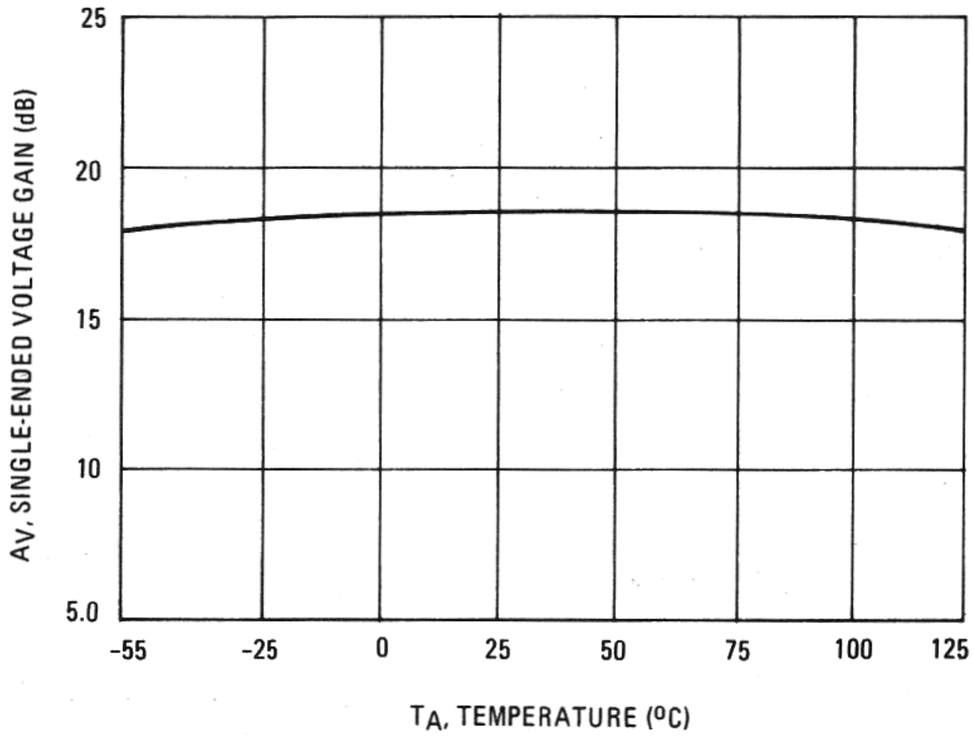


FIGURE 3 – VOLTAGE GAIN versus POWER SUPPLY VOLTAGES

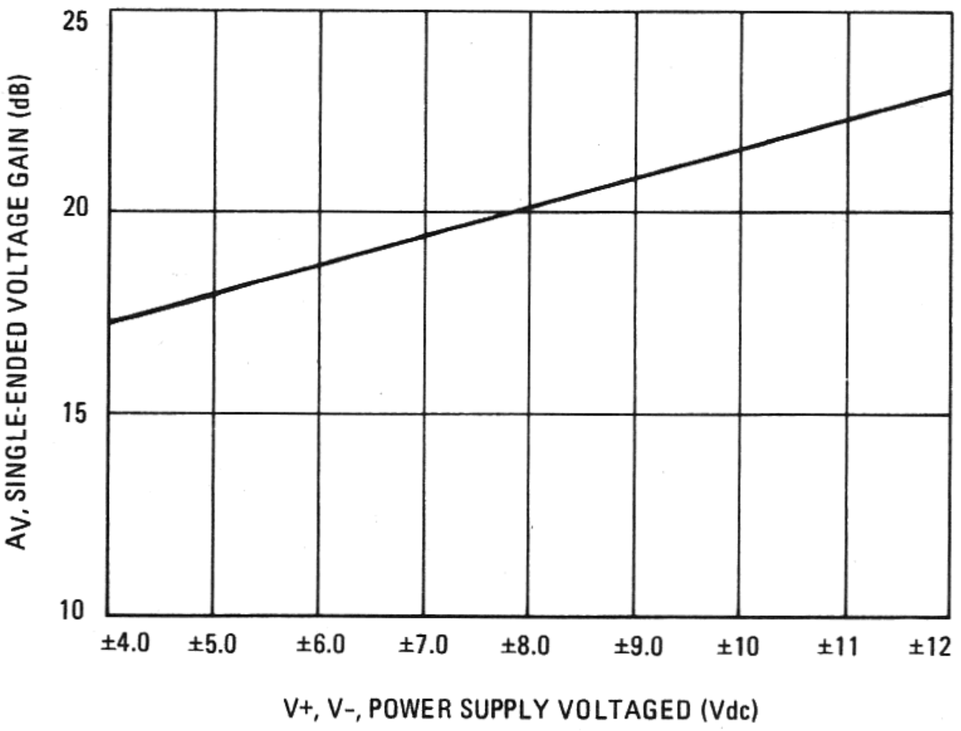


FIGURE 4 – OUTPUT VOLTAGE SWING versus LOAD RESISTANCE

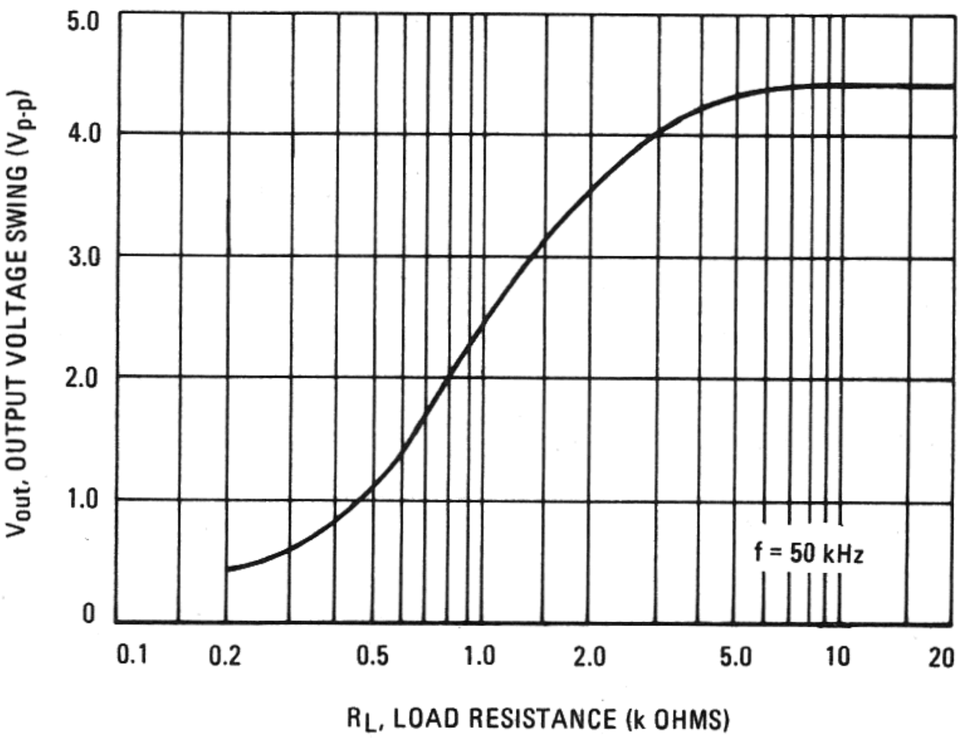


FIGURE 5 – INPUT Cp AND Rp versus FREQUENCY (BOTH CHANNELS)

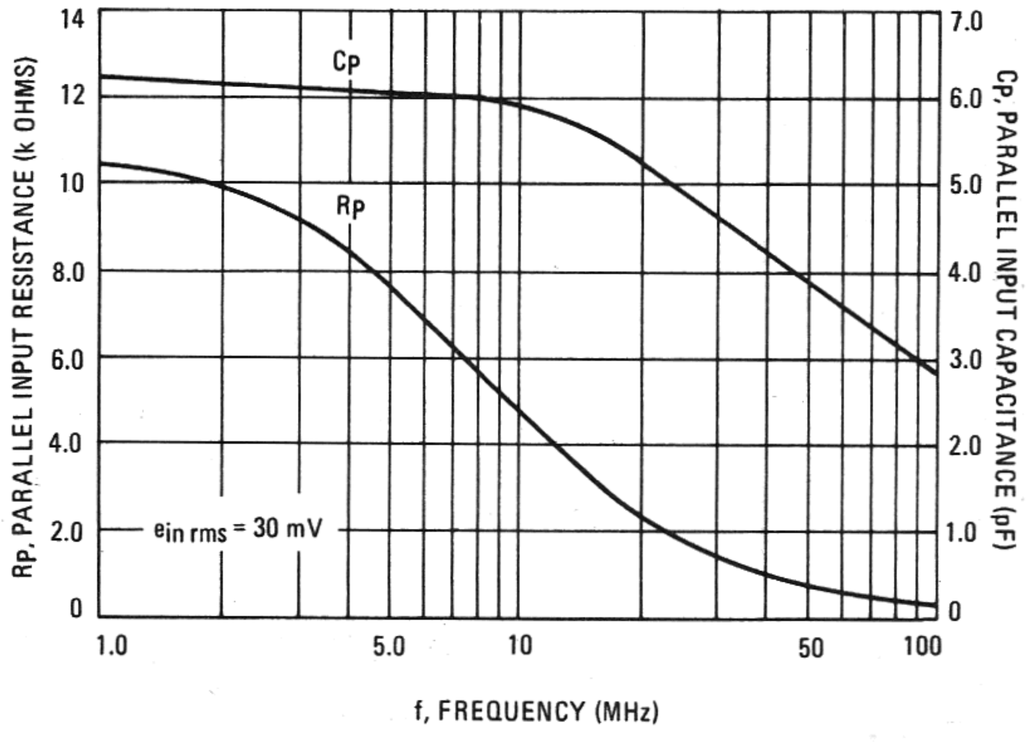
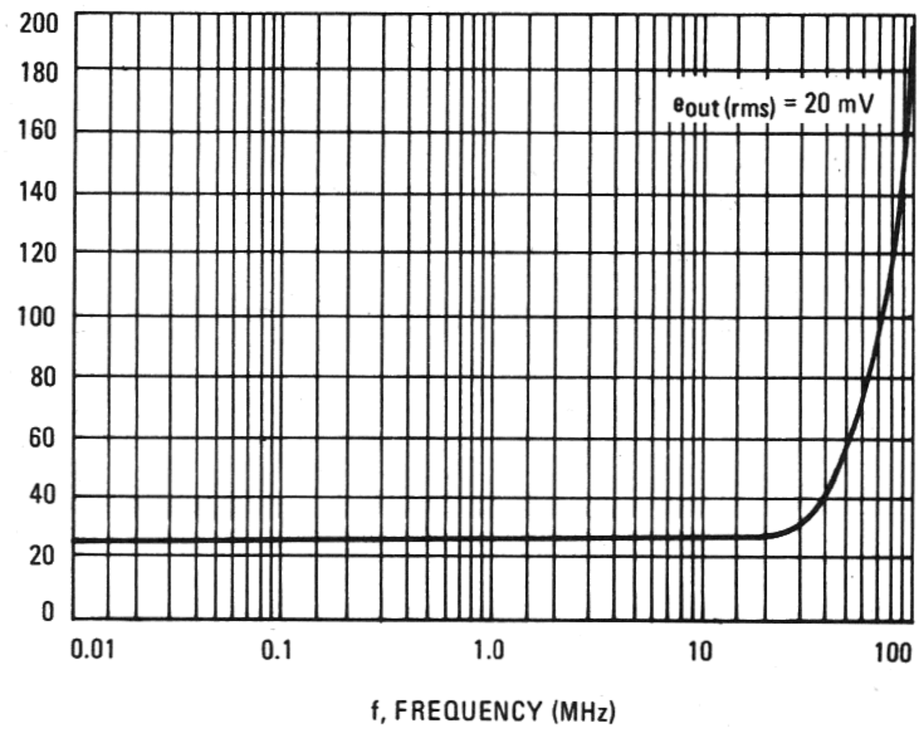


FIGURE 6 – OUTPUT IMPEDANCE versus FREQUENCY



MC1545, MC1445 (continued)

FIGURE 7 – CHANNEL SEPARATION versus FREQUENCY

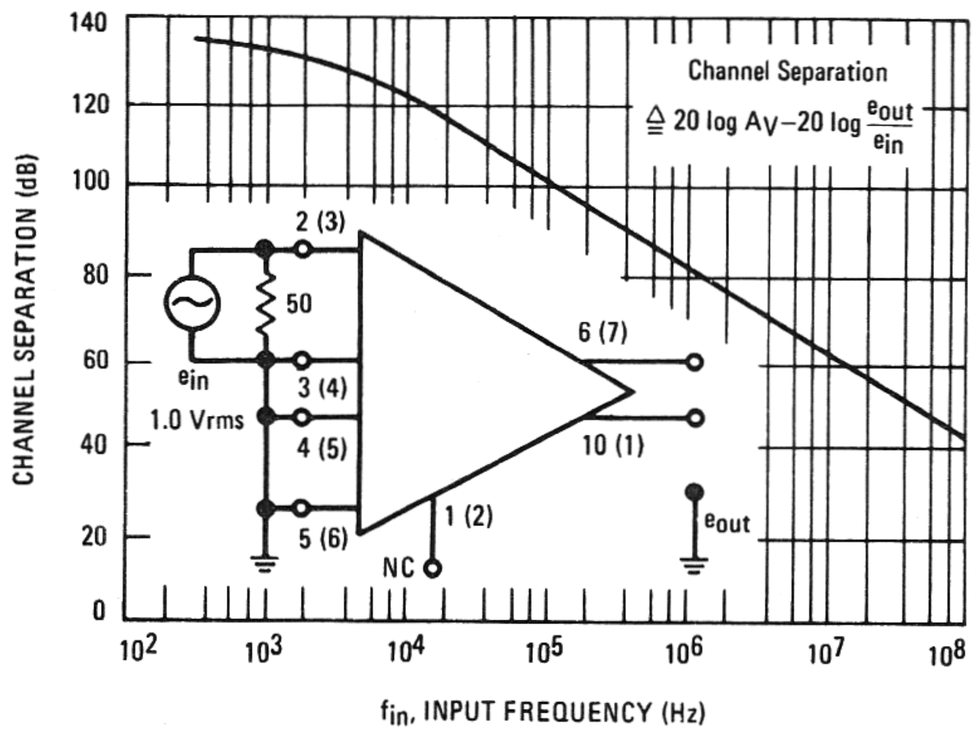


FIGURE 8 – GATE CHARACTERISTICS

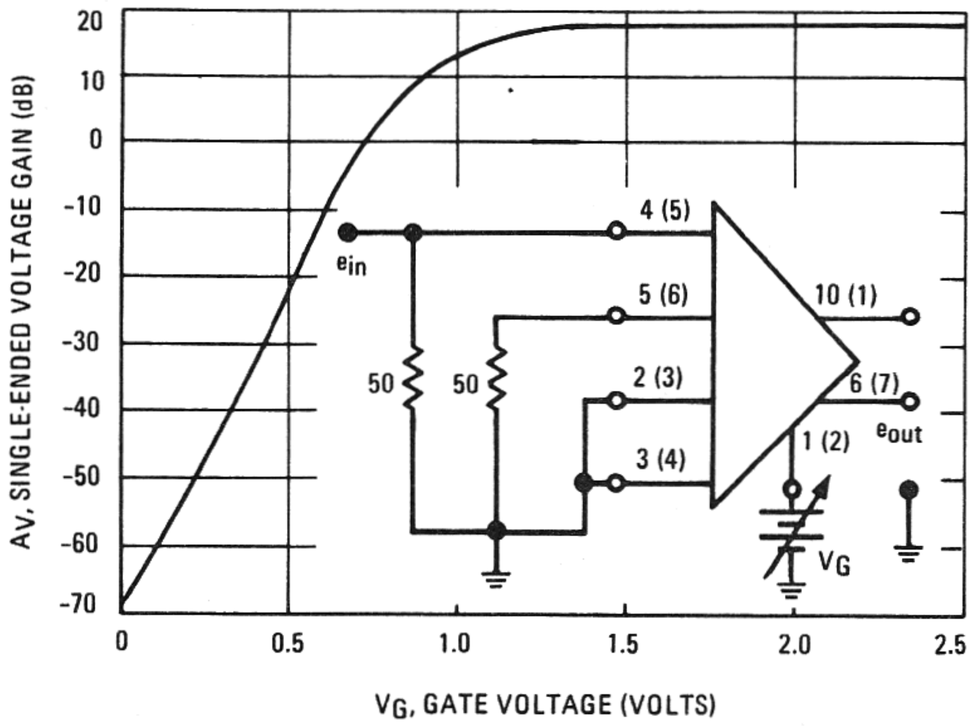


FIGURE 9 – COMMON MODE REJECTION RATIO versus FREQUENCY

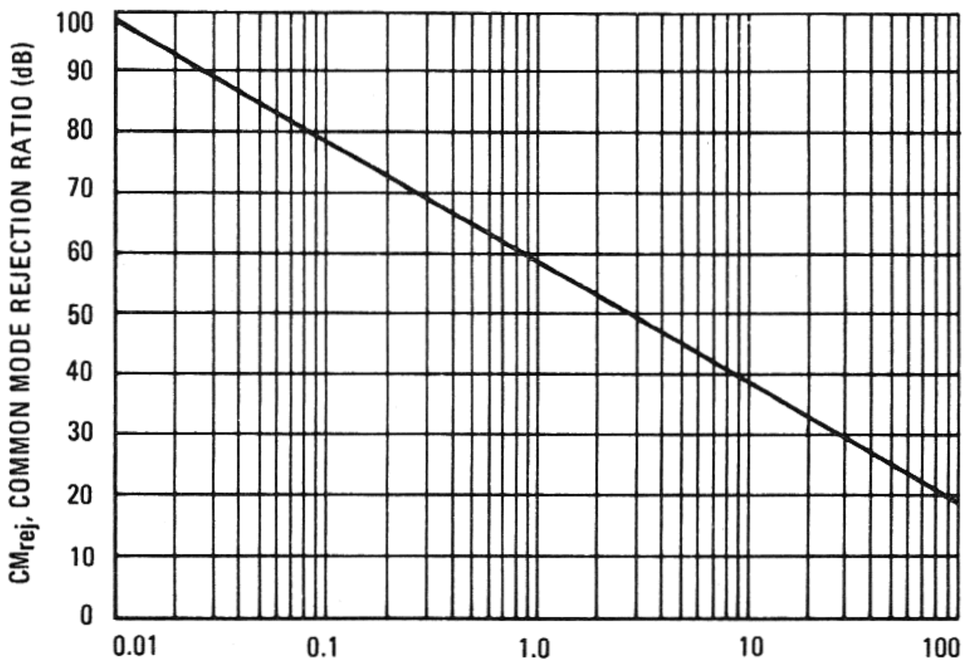


FIGURE 10 – INPUT WIDEBAND NOISE versus SOURCE RESISTANCE

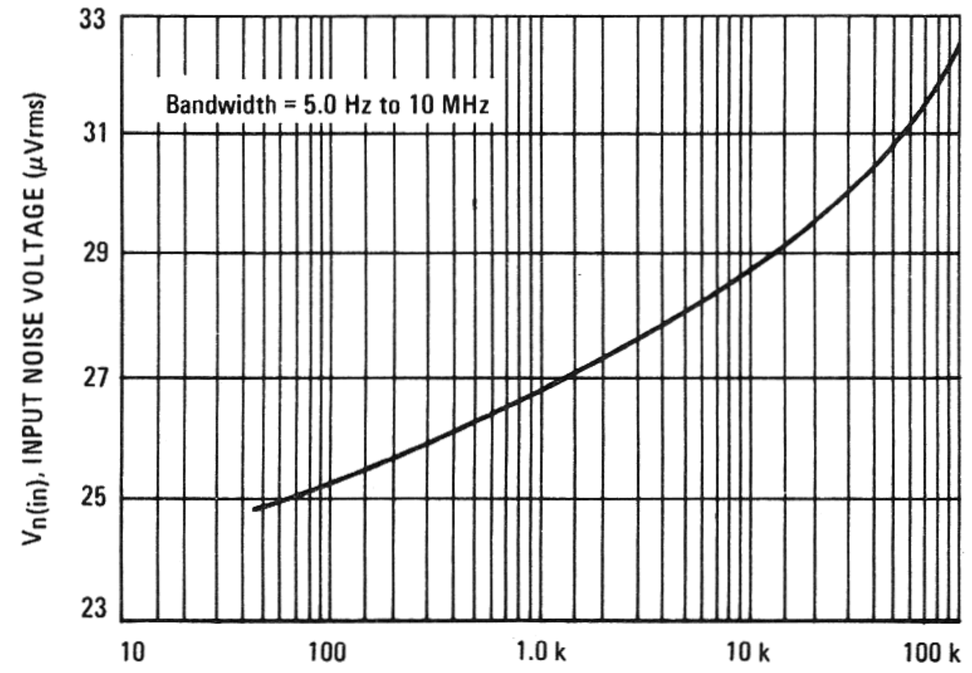


FIGURE 11 – POWER DISSIPATION versus POWER SUPPLY VOLTAGE

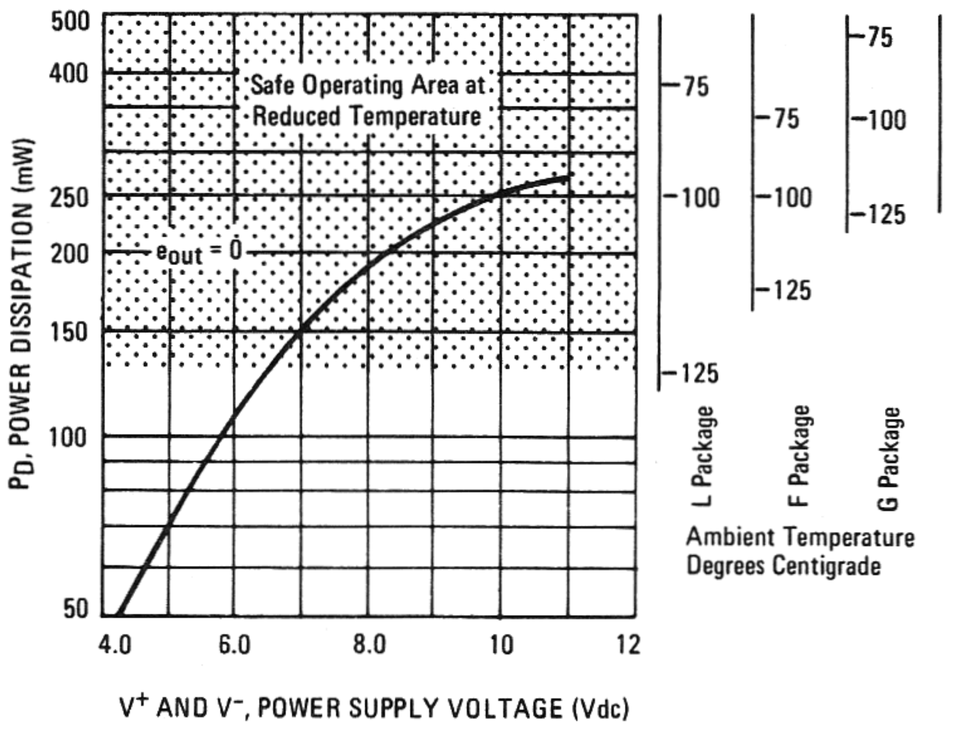
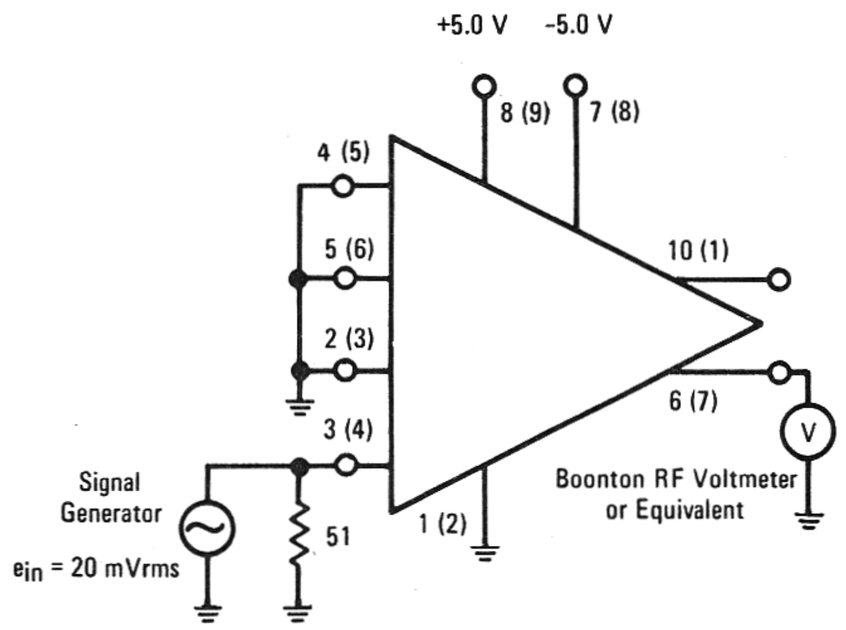


FIGURE 12 – SINGLE-ENDED VOLTAGE GAIN AND BANDWIDTH TEST CIRCUIT



Number in parenthesis denotes pin for F and L packages, number at left in each case denotes corresponding pin for G package.

MC1545, MC1445 (continued)

FIGURE 13 – OUTPUT VOLTAGE SWING TEST CIRCUIT

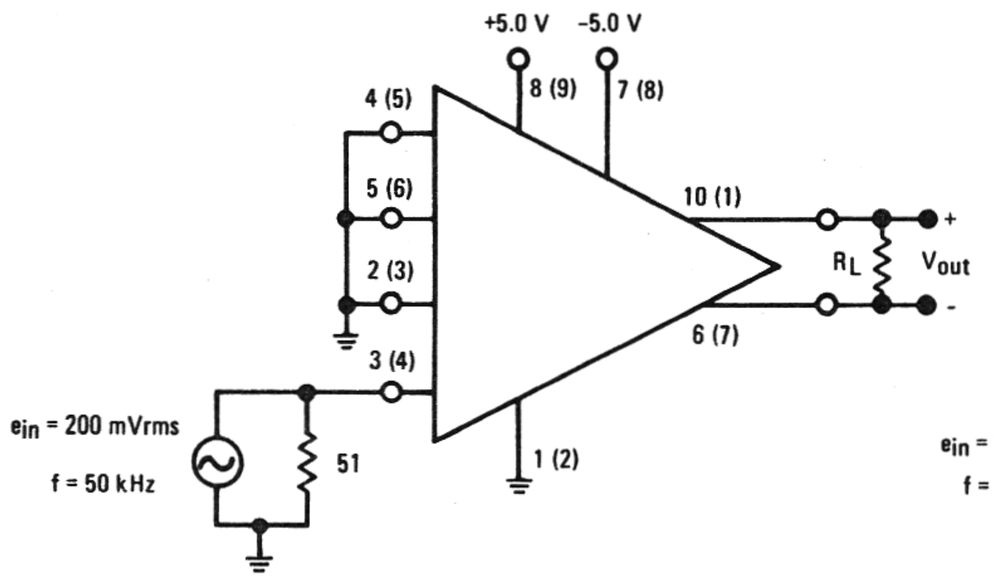


FIGURE 14 – INPUT IMPEDANCE TEST CIRCUIT

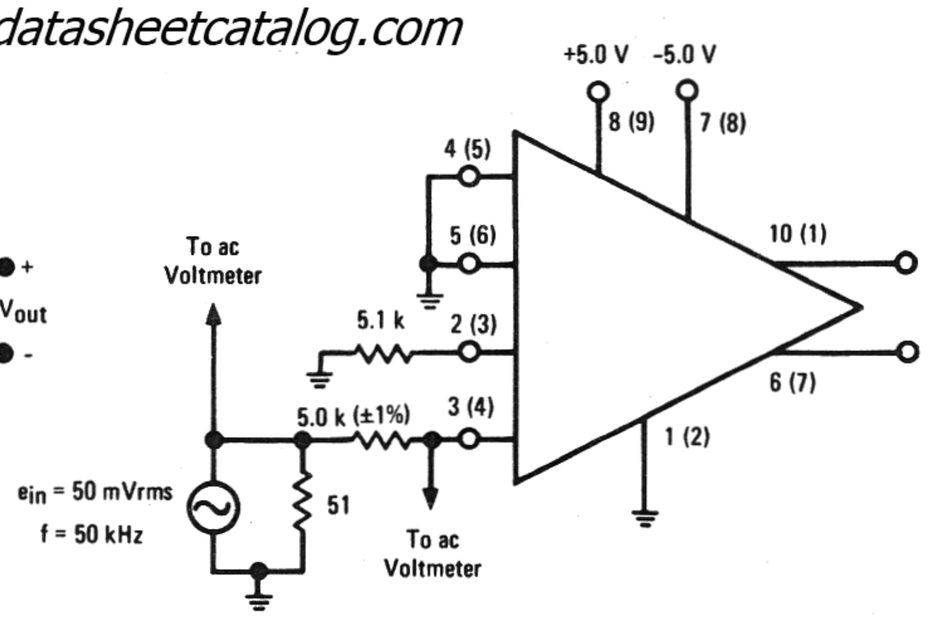


FIGURE 15 – OUTPUT IMPEDANCE TEST CIRCUIT

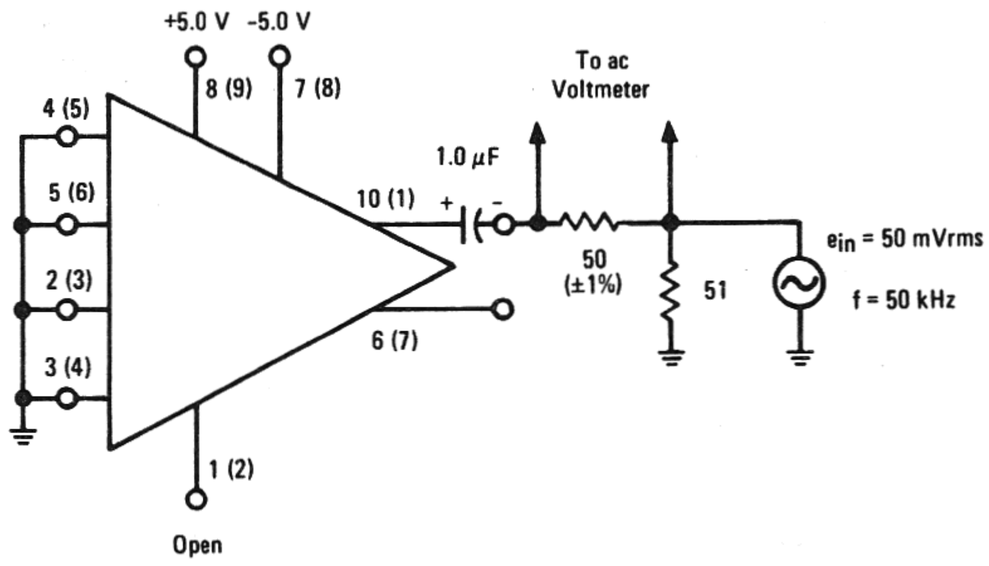


FIGURE 16 – INPUT BIAS CURRENT AND INPUT OFFSET CURRENT TEST CIRCUIT

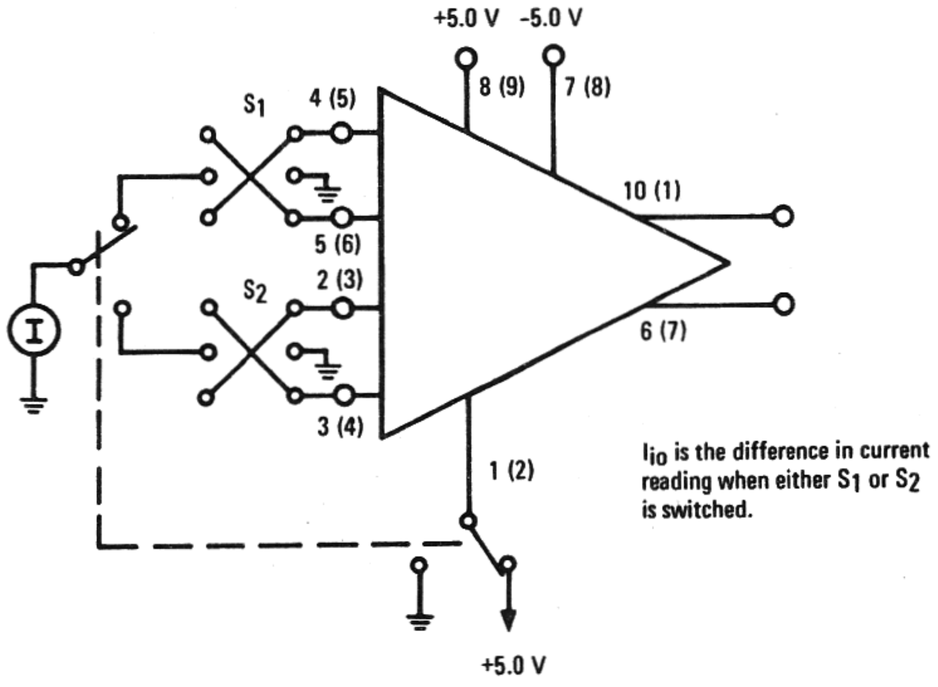


FIGURE 17 – INPUT OFFSET VOLTAGE AND QUIESCENT OUTPUT LEVEL TEST CIRCUIT

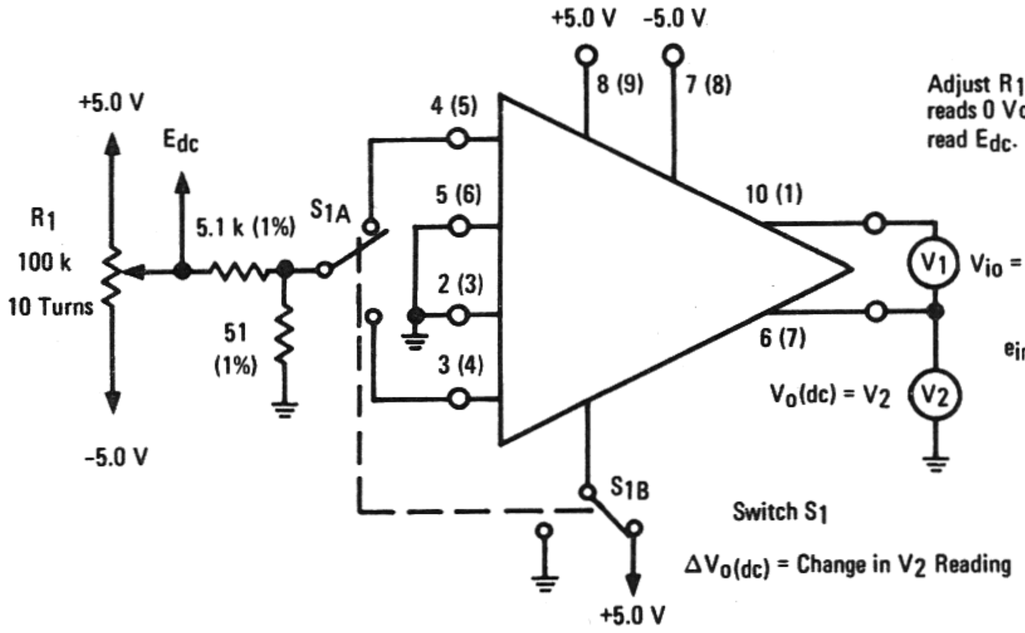
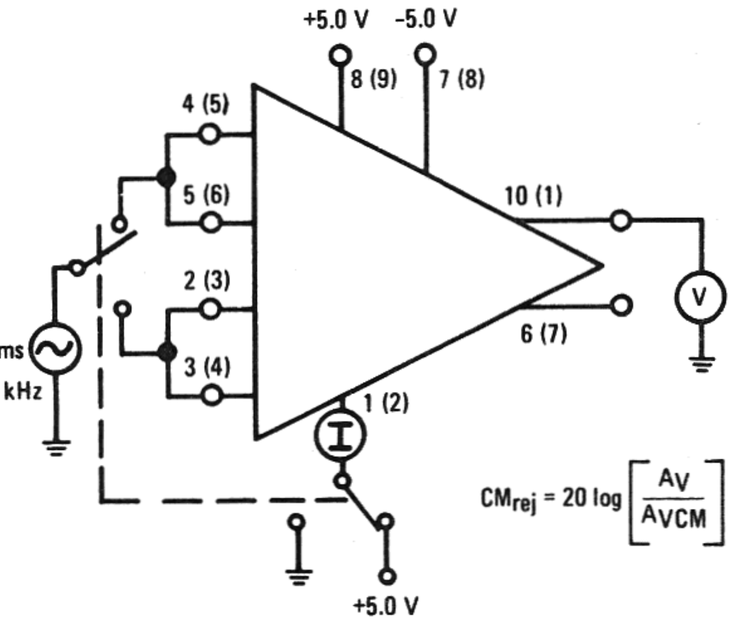


FIGURE 18 – GATE CURRENT (HIGH AND LOW), COMMON-MODE REJECTION AND COMMON-MODE INPUT RANGE TEST CIRCUIT



Number in parenthesis denotes pin for F and L packages, number at left in each case denotes corresponding pin for G package.

MC1545, MC1445 (continued)

FIGURE 19 – PROPAGATION DELAY AND RISE AND FALL TIMES TEST CIRCUIT

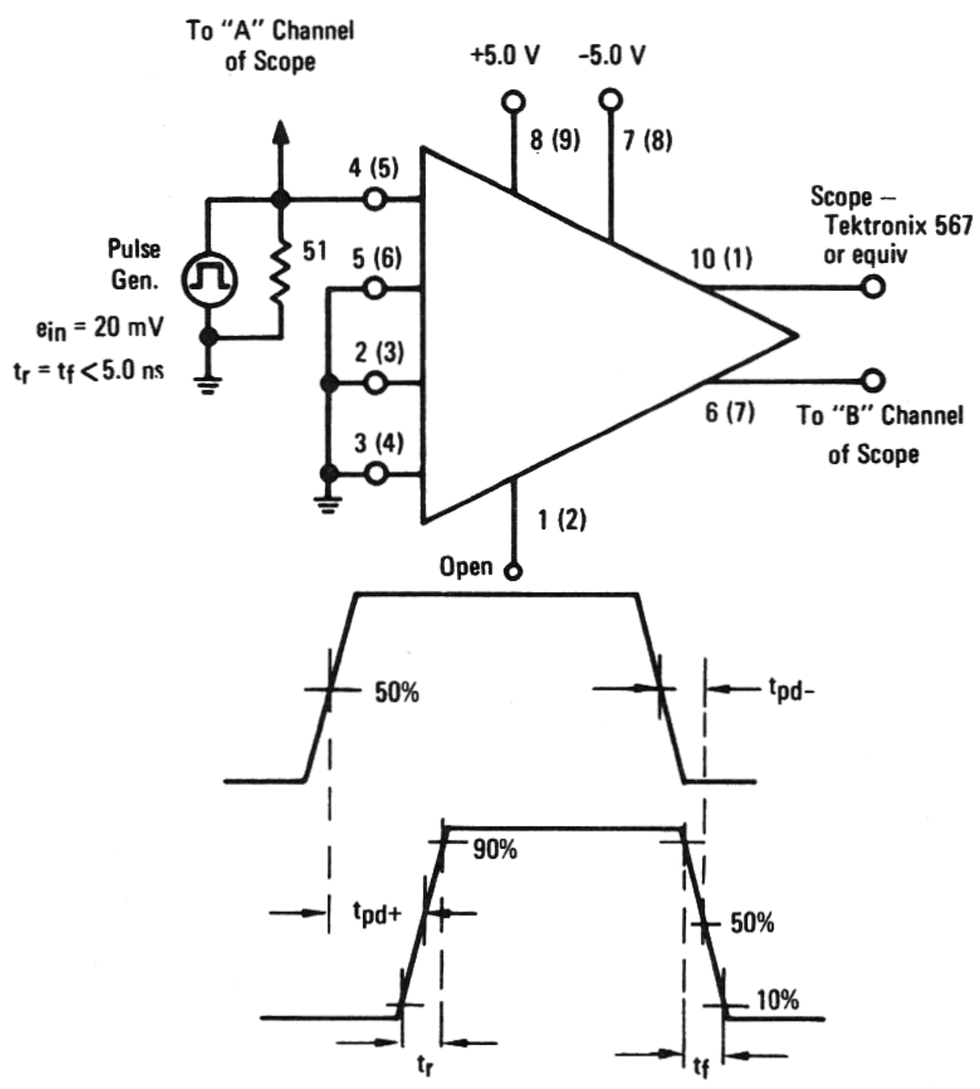
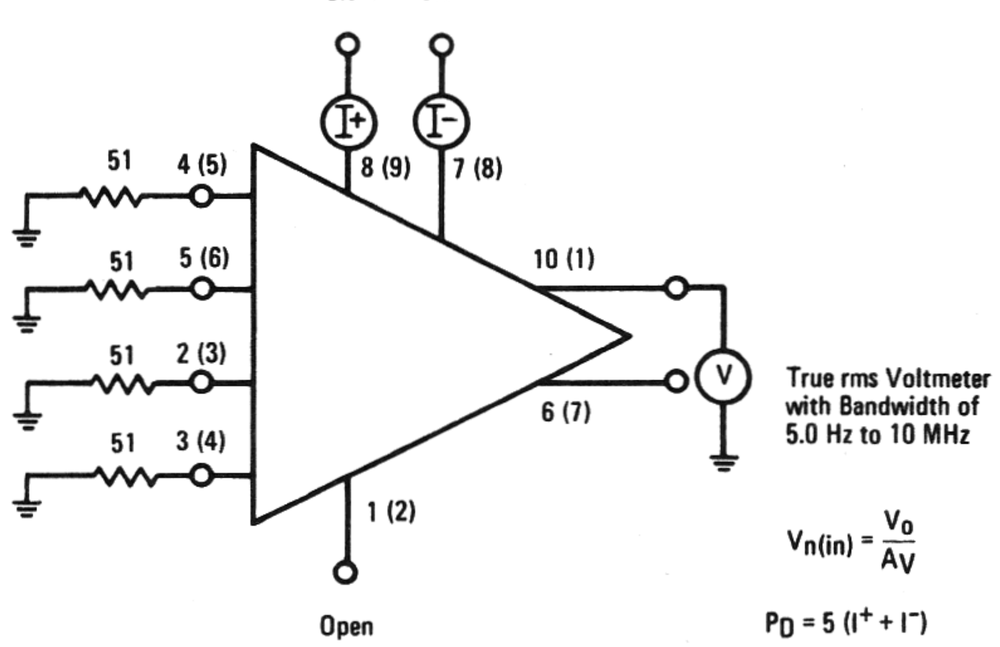


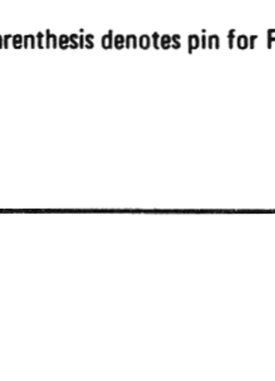
FIGURE 20 – POWER DISSIPATION AND WIDEBAND INPUT NOISE TEST CIRCUIT



Number in parenthesis denotes pin for F and L packages, number at left in each case denotes corresponding pin for G package.

CASE OUTLINES

G SUFFIX
METAL PACKAGE
CASE 602A

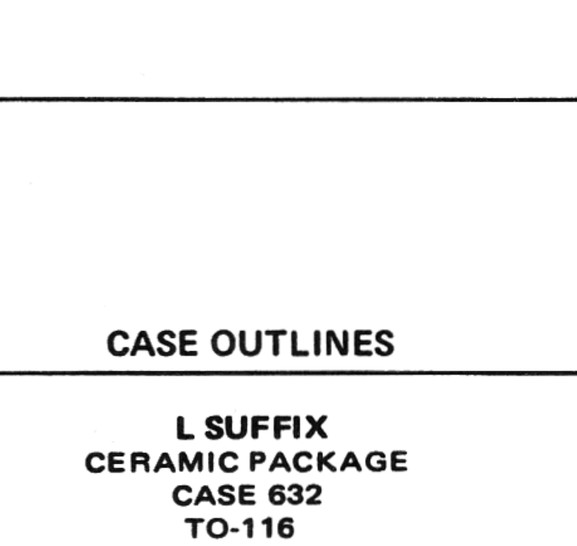


(Bottom View)

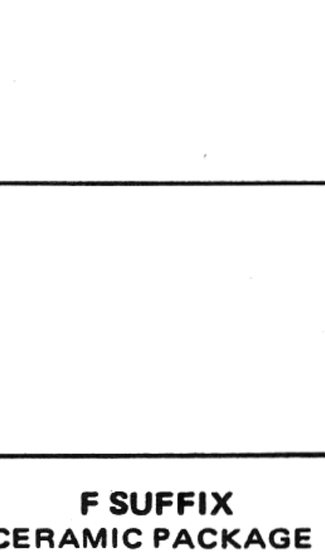
Pin 7 connected to case

Weight = 0.918 grams (approx.)

L SUFFIX
CERAMIC PACKAGE
CASE 632
TO-116



F SUFFIX
CERAMIC PACKAGE
CASE 607
TO-86



Lead 1 identified by color dot or by elbow on lead. All leads electrically isolated from package.

Weight = 0.218 grams (approx.)